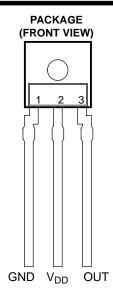


TSL260R, TSL261R, TSL262R INFRARED LIGHT-TO-VOLTAGE OPTICAL SENSORS

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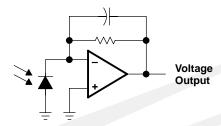
- Integral Visible Light Cutoff Filter
- Monolithic Silicon IC Containing Photodiode, Operational Amplifier, and Feedback Components
- Converts Light Intensity to a Voltage
- High Irradiance Responsivity, Typically
 111 mV/(μW/cm²) at λ_p = 940 nm (TSL260R)
- Compact 3-Lead Plastic Package
- Single Voltage Supply Operation
- Low Dark (Offset) Voltage....10mV Max
- Low Supply Current.....1.1 mA Typical
- Wide Supply-Voltage Range.... 2.7 V to 5.5 V
- Replacements for TSL260, TSL261, and TSL262



Description

The TSL260R, TSL261R, and TSL262R are infrared light-to-voltage optical sensors, each combining a photodiode and a transimpedance amplifier (feedback resistor = 16 M Ω , 8 M Ω , and 2.8 M Ω respectively) on a single monolithic IC. Output voltage is directly proportional to the light intensity (irradiance) on the photodiode. These devices have improved amplifier offset-voltage stability and low power consumption and are supplied in a 3-lead plastic sidelooker package with an integral visible light cutoff filter and lens.

Functional Block Diagram



Terminal Functions

TERMINAL		DECODIFICAL
NAME	NO.	DESCRIPTION
GND	1	Ground (substrate). All voltages are referenced to GND.
OUT	3	Output voltage
V_{DD}	2	Supply voltage

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Absolute Maximum Ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V _{DD} (see Note 1)	6 \
Output current, IO	±10 mA
Duration of short-circuit current at (or below) 25°C (see Note 2)	5 9
Operating free-air temperature range, T _A	25°C to 85°C
Storage temperature range, T _{stg}	25°C to 85°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	240°C

NOTES: 1. All voltages are with respect to GND.

2. Output may be shorted to supply.

Recommended Operating Conditions

	MIN	NOM MA	UNIT
Supply voltage, V _{DD}	2.7	5.	5 V
Operating free-air temperature, T _A	0	7) °C

Electrical Characteristics at V_{DD} = 5 V, T_A = 25°C, λp = 940 nm, R_L = 10 k Ω (unless otherwise noted) (see Notes 3, 4, and 5)

DADAMETED		TEST	TSL260R			TSL261R			TSL262R				
	PARAMETER	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
V_{D}	Dark voltage	$E_e = 0$	0	4	10	0	4	10	0	4	10	mV	
V _{OM}	Maximum output voltage	V _{DD} = 4.5 V	3	3.3		3	3.3		3	3.3		V	
		$E_e = 18 \mu\text{W/cm}^2$	1	2	3								
Vo	Output voltage	$E_e = 46 \mu\text{W/cm}^2$				1	2	3				V	
L	-	$E_e = 220 \mu\text{W/cm}^2$							1	2	3		
	Temperature coefficient of output voltage (V _O)	$E_e = 18 \mu W/cm^2$, $T_A = 0^{\circ}C \text{ to } 70^{\circ}C$		8								mV/°C	
				0.4								%/°C	
		$E_e = 46 \mu \text{W/cm}^2$,					8					mV/°C	
α_{VO}		$T_A = 0$ °C to 70 °C					0.4					%/°C	
		(V _O)	$E_e = 220 \mu\text{W/cm}^2$								8		mV/°C
		$T_A = 0$ °C to 70 °C								0.4		%/°C	
N _e	Irradiance responsivity	See Note 6		111			43.5			9.1		mV/(μW/cm ²)	
	Supply current	$E_e = 18 \mu\text{W/cm}^2$		1.1	1.7								
I _{DD}		$E_e = 46 \mu\text{W/cm}^2$					1.1	1.7				mA	
		$E_e = 220 \mu\text{W/cm}^2$								1.1	1.7		

NOTES: 3. Measurements are made with R $_{L}$ = 10 $k\Omega$ between output and ground.

- 4. Optical measurements are made using small-angle incident radiation from an LED optical source.
- 5. The input irradiance E_e is supplied by a GaAs LED with peak wavelength λ_p = 940 nm
- 6. Irradiance responsivity is characterized over the range $V_O = 0.05$ to 2.9 V. The best-fit straight line of Output Voltage V_O versus irradiance E_e over this range will typically have a positive extrapolated V_O value for $E_e = 0$.



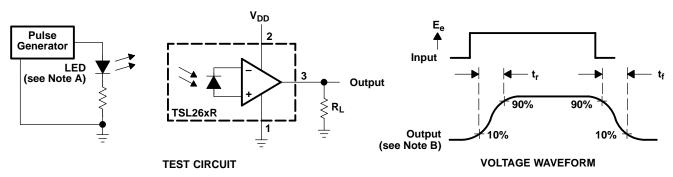
[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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Dynamic Characteristics at $T_A = 25$ °C (see Figure 1)

PARAMETER		TEGT CONDITIONS	TSL260R			TSL261R			TSL262R			
		TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
t _r	Output pulse rise time	$V_{DD} = 5 \text{ V}, \lambda_p = 940 \text{ nm}$		260			70			7		μs
t _f	Output pulse fall time	$V_{DD} = 5 \text{ V}, \lambda_p = 940 \text{ nm}$		260			70			7		μs
V _n	Output noise voltage	$V_{DD} = 5 \text{ V}, E_e = 0,$ f = 1000 Hz		0.8			0.7			0.6		μV/√ Hz

PARAMETER MEASUREMENT INFORMATION



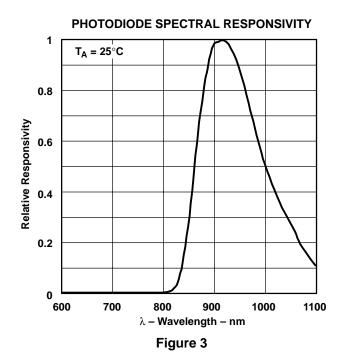
NOTES: A. The input irradiance is supplied by a pulsed GaAs light-emitting diode with the following characteristics: λ_p = 940 nm, $t_f < 1 \ \mu s$.

B. The output waveform is monitored on an oscilloscope with the following characteristics: $t_{\Gamma} < 100$ ns, $Z_{i} \ge 1$ M Ω , $C_{i} \le 20$ pF.

Figure 1. Switching Times

TYPICAL CHARACTERISTICS

OUTPUT VOLTAGE IRRADIANCE 10 V_{DD} = 5 V TSL261R $\lambda_p = 940 \text{ nm}$ $R_L^{r} = 10 \text{ k}\Omega$ T_A = 25°C Vo — Output Voltage — V TSL260R TSL262R 0.1 0.01 0.1 10 100 1000 E_e — Irradiance — μ W/cm²



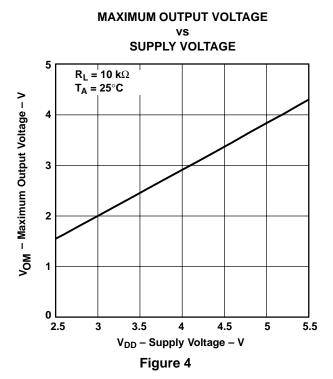
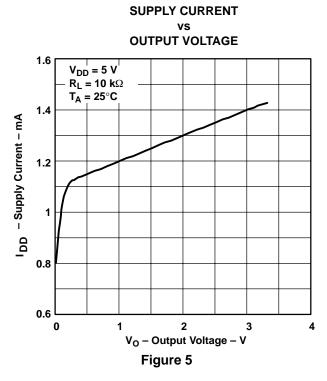


Figure 2



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TYPICAL CHARACTERISTICS

NORMALIZED OUTPUT VOLTAGE

vs ANGULAR DISPLACEMENT

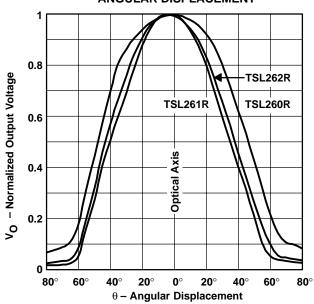


Figure 6

MECHANICAL INFORMATION

The device is supplied in a plastic three-lead package. The integrated photodiode active area is typically 1.0 mm^2 (0.0016 in^2) for TSL260R, 0.5 mm^2 (0.00078 in^2) for the TSL261R, and 0.26 mm^2 (0.0004 in^2) for the TSL262R.

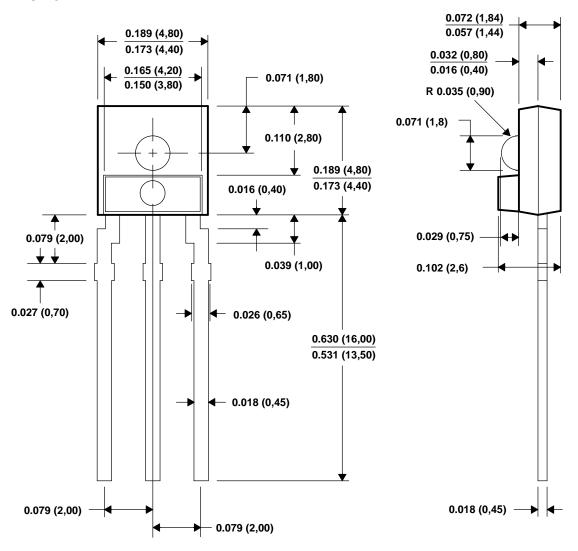


Figure 7. Package Configuration

NOTES: A. All linear dimensions are in inches (millimeters).

- B. All dimensions apply before solder dip.
- C. Package body is a nonfilled optically transparent material
- D. Index of refraction of clear plastic is 1.55.
- E. This drawing is subject to change without notice.



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